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## **FEATURES**

- WIDE SUPPLY RANGE ±10 to ±45V
- HIGH OUTPUT CURRENT ±10A Peak
- LOW COST Class "C" output stage
- LOW QUIESCENT CURRENT 3mA

## **APPLICATIONS**

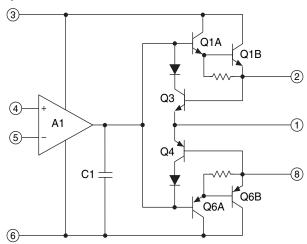
- PROGRAMMABLE POWER SUPPLY
- MOTOR/SYNCRO DRIVER
- VALVE AND ACTUATOR CONTROL
- DC OR AC POWER REGULATOR
- FIXED FREQUENCY POWER OSCILLATOR

## **DESCRIPTION**

The PA61 and PA61A are high output current operational amplifiers designed to drive resistive, inductive and capacitive loads. Their complementary emitter follower output stage is the simple class C type and optimized for low frequency applications where crossover distortion is not critical. These amplifiers are not recommended for audio, transducer or deflection coil drive circuits above 1kHz or when distortion is critical. The safe operating area (SOA) is fully specified and can be observed for all operating conditions by selection of user programmable current limiting resistors. Both amplifiers are internally compensated for all gain settings. For continuous operation under load, mounting on a heatsink of proper rating is recommended.

This hybrid circuit utilizes thick film conductors, ceramic capacitors, and semiconductor chips to maximize reliability, minimize size, and give top performance. Ultrasonically bonded aluminum wires provide reliable interconnections at all operating temperatures. The 8-pin TO-3 package is electrically isolated and hermetically sealed. The use of compressible thermal washers and/or improper mounting torque voids the product warranty. Please see "General Operating Considerations".

## **EQUIVALENT SCHEMATIC**





8-PIN TO-3
PACKAGE STYLE CE

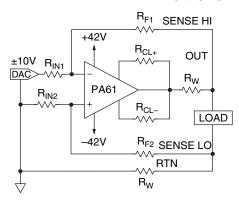


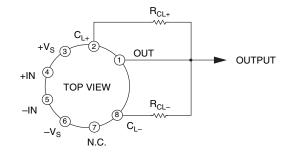
FIGURE 1. PROGRAMMABLE POWER SUPPLY WITH REMOTE SENSING

## TYPICAL APPLICATION

Due to its high current drive capability, PA61 applications often utilize remote sensing to compensate IR drops in the wiring. The importance of remote sensing increases as accuracy requirements, output currents, and distance between amplifier and load go up. The circuit above shows wire resistance from the PA61 to the load and back to the local ground via the power return line. Without remote sensing, a 7.5A load current across only 0.05 ohm in each line would produce a 0.75V error at the load.

With the addition of the second ratio matched  $R_{\rm F}/R_{\rm IN}$  pair and two low current sense wires, IR drops in the power return line become common mode voltages for which the op amp has a very high rejection ratio. Voltage drops in the output and power return wires are inside the feedback loop. Therefore, as long as the Power Op Amp has the voltage drive capability to overcome the IR losses, accuracy remains the same. Application Note 7 presents a general discussion of PPS circuits.

## **EXTERNAL CONNECTIONS**



#### ABSOLUTE MAXIMUM RATINGS

90V SUPPLY VOLTAGE, +Vs to -Vs OUTPUT CURRENT, within SOA 10A POWER DISSIPATION, internal 97W INPUT VOLTAGE, differential  $\pm V_s - 3V$ INPUT VOLTAGE, common mode ±V<sub>s</sub> 300°C TEMPERATURE, pin solder-10s TEMPERATURE, junction<sup>1</sup> 200°C TEMPERATURE RANGE, storage -65 to +150°C OPERATING TEMPERATURE RANGE, case -55 to +125°C

#### **SPECIFICATIONS**

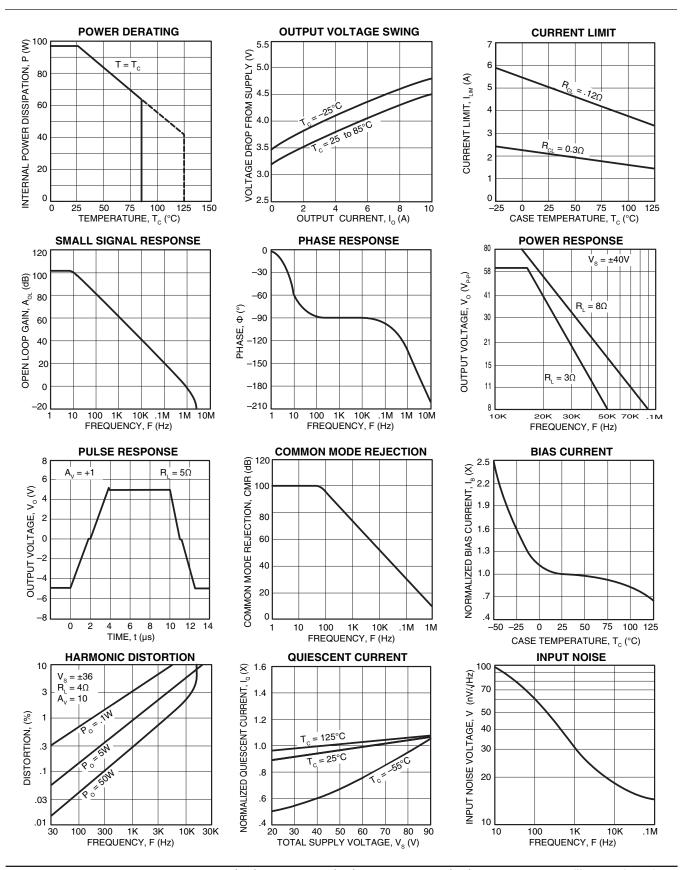
SPECIFICATIONS PA61 PA61A									
PARAMETER	TEST CONDITIONS 2	MIN	TYP	MAX	MIN	TYP	MAX	UNITS	
INPUT OFFSET VOLTAGE, initial OFFSET VOLTAGE, vs. temperature OFFSET VOLTAGE, vs. supply OFFSET VOLTAGE, vs. power BIAS CURRENT, initial BIAS CURRENT, vs. temperature BIAS CURRENT, vs. supply OFFSET CURRENT, initial OFFSET CURRENT, vs. temperature INPUT IMPEDANCE, DC INPUT CAPACITANCE COMMON MODE VOLTAGE RANGE <sup>3</sup> COMMON MODE REJECTION, DC <sup>3</sup>	$T_c$ = 25°C Specified temperature range $T_c$ = 25°C $T_c$ = 25°C $T_c$ = 25°C Specified temperature range $T_c$ = 25°C Specified temperature range $T_c$ = 25°C $T_c$ = 25°C Specified temperature range Specified temperature range Specified temperature range	±V <sub>s</sub> -5	±2 ±10 ±30 ±20 12 ±50 ±10 ±12 ±50 200 3 ±V <sub>s</sub> -3	±6 ±65 ±200 30 ±500	*	±1	±4 ±40 * 20 *	mV μV/°C μV/V μV/W nA pA/°C pA/V nA pA/°C MΩ pF V dB	
GAIN OPEN LOOP GAIN at 10Hz GAIN BANDWIDTH PRODUCT at 1MHz POWER BANDWIDTH PHASE MARGIN	Full temp. range, full load $T_c = 25^{\circ}\text{C}$ , full load $T_c = 25^{\circ}\text{C}$ , $I_o = 8\text{A}$ , $V_o = 40\text{V}_{PP}$ Full temperature range	96 10	108 1 16 45		*	* * *		dB MHz kHz	
OUTPUT  VOLTAGE SWING³  VOLTAGE SWING³  VOLTAGE SWING³  CURRENT  SETTLING TIME to .1%  SLEW RATE  CAPACITIVE LOAD, unit gain  CAPACITIVE LOAD, gain>4	$T_{\rm c}=25^{\circ}{\rm C},\ I_{\rm o}=10{\rm A}$ Full temp. range, $I_{\rm o}=4{\rm A}$ Full temp. range, $I_{\rm o}=68{\rm mA}$ $T_{\rm c}=25^{\circ}{\rm C}$ $T_{\rm c}=25^{\circ}{\rm C}$ , $2{\rm V}$ step $T_{\rm c}=25^{\circ}{\rm C}$ , $R_{\rm c}=6\Omega$ Full temperature range Full temperature range	±V <sub>S</sub> -7 ±V <sub>S</sub> -6 ±V <sub>S</sub> -5 ±10	±V <sub>S</sub> -5 ±V <sub>S</sub> -4	1.5 SOA	±V <sub>S</sub> -6 * * *	* * *	*	V V V A µs V/µs nF	
POWER SUPPLY VOLTAGE CURRENT, quiescent	Full temperature range $T_c = 25^{\circ}C$	±10	±32 3	±45 10	*	*	*	V mA	
THERMAL RESISTANCE, AC, junction to case <sup>4</sup> RESISTANCE, DC, junction to case RESISTANCE, junction to air TEMPERATURE RANGE, case	F > 60Hz F < 60Hz Meets full range specification	-25	1.0 1.5 30 25	1.2 1.8 +85	*	* * *	* *	°C/W °C/W °C/W °C	

#### NOTES: \*

- The specification of PA61A is identical to the specification for PA61 in applicable column to the left.
- 1. Long term operation at the maximum junction temperature will result in reduced product life. Derate internal power dissipation to achieve high MTTF.
- The power supply voltage for all specifications is the TYP rating unless noted as a test condition.
- +V<sub>s</sub> and -V<sub>s</sub> denote the positive and negative supply rail respectively. Total V<sub>s</sub> is measured from +V<sub>s</sub> to -V<sub>s</sub>.
   Rating applies if the output current alternates between both output transistors at a rate faster than 60Hz.

CAUTION

The internal substrate contains beryllia (BeO). Do not break the seal. If accidentally broken, do not crush, machine, or subject to temperatures in excess of 850°C to avoid generating toxic fumes.



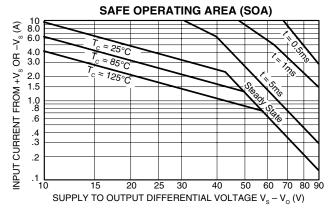
#### **GENERAL**

Please read Application Note 1 "General Operating Considerations" which covers stability, supplies, heat sinking, mounting, current limit, SOA interpretation, and specification interpretation. Visit www.apexmicrotech.com for design tools that help automate tasks such as calculations for stability, internal power dissipation, current limit and heat sink selection. The "Application Notes" and "Technical Seminar" sections contain a wealth of information on specific types of applications. Package outlines, heat sinks, mounting hardware and other accessories are located in the "Packages and Accessories" section. Evaluation Kits are available for most Apex product models, consult the "Evaluation Kit" section for details. For the most current version of all Apex product data sheets, visit www.apexmicrotech.com.

## SAFE OPERATING AREA (SOA)

The output stage of most power amplifiers has 3 distinct limitations:

- 1. The current handling capability of the transistor geometry and the wire bonds.
- 2. The second breakdown effect which occurs whenever the simultaneous collector current and collector-emitter voltage exceeds specified limits.
- 3. The junction temperature of the output transistors.



The SOA curves combine the effect of all limits for this Power Op Amp. For a given application, the direction and magnitude of the output current should be calculated or measured and checked against the SOA curves. This is simple for resistive loads but more complex for reactive and EMF generating loads. The following guidelines may save extensive analytical efforts.

1. Under transient conditions, capacitive and dynamic\* inductive loads up to the following maximum are safe:

CAPACITIVE LOAD			INDUCTIV	INDUCTIVE LOAD			
$V_s$	$I_{LIM} = 5A$	$I_{LIM} = 10A$	$I_{LIM} = 5A$	$I_{LIM} = 10A$			
45V	200 F	150 F	8mH	2.8mH			
40V	400 F	200 F	11mH	4.3mH			
35V	800 F	400 F	20mH	5.0mH			
30V	1600 F	800 F	35mH	6.2mH			
25V	5.0mF	2.5mF	50mH	15mH			
20V	10mF	5.0mF	400mH	20mH			
15V	20mF	10mF	**	100mH			

- If the inductive load is driven near steady state conditions, allowing the output voltage to drop more than 8V below the supply rail with  $I_{LIM} = 10A$  or 15V below the supply rail with  $I_{LIM} = 5A$  while the amplifier is current limiting, the inductor should be capacitively coupled or the current limit must be lowered to meet SOA criteria.
- Second breakdown effect imposes no limitation but thermal limitations must still be observed.
- 2. The amplifier can handle any EMF generating or reactive load and short circuits to the supply rail or shorts to common if the current limits are set as follows at T<sub>c</sub>=85°C.

±٧s	SHORT TO $V_s$ ± C, L, OR EMF LOAD	SHORT TO COMMON
45V	0.1A	1.3A
40V	0.2A	1.5A
35V	0.3A	1.6A
30V	0.5A	2.0A
25V	1.2A	2.4A
20V	1.5A	3.0A
15V	2.0A	4.0A

These simplified limits may be exceeded with further analysis using the operating conditions for a specific application.

3. The output stage is protected against transient flyback. However, for protection against sustained, high energy flyback, external fast-recovery diodes should be used.